

### Absolute maximum ratings (T<sub>a</sub>=25°C)

Symbol	Ratings	Unit
V <sub>CB0</sub>	-100	V
V <sub>CEO</sub>	-100	V
V <sub>EBO</sub>	-6	V
I <sub>c</sub>	-5	A
I <sub>CP</sub>	-8 (PW≤1ms, D <sub>u</sub> ≤50%)	A
I <sub>B</sub>	-0.5	A
I <sub>F</sub>	-5 (PW≤0.5ms, D <sub>u</sub> ≤25%)	A
I <sub>FSM</sub>	-8 (PW≤10ms, single)	A
V <sub>R</sub>	120	V
P <sub>T</sub>	5 (T <sub>a</sub> =25°C) 25 (T <sub>c</sub> =25°)	W
V <sub>ISO</sub>	1000 (Between fin and lead pin, AC)	V <sub>rms</sub>
T <sub>j</sub>	150	°C
T <sub>stg</sub>	-40 to +150	°C
θ <sub>J-c</sub>	5	°C/W

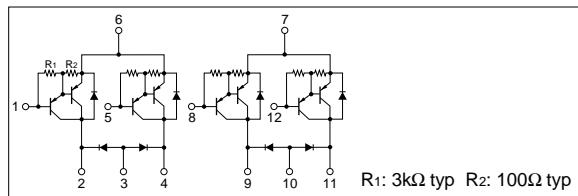
### Electrical characteristics (T<sub>a</sub>=25°C)

Symbol	Specification			Unit	Conditions
	min	typ	max		
I <sub>CB0</sub>			-10	μA	V <sub>CB</sub> =-100V
I <sub>EBO</sub>			-10	mA	V <sub>EB</sub> =-6V
V <sub>CEO</sub>	-100			V	I <sub>c</sub> =-10mA
h <sub>FE</sub>	2000	5000	15000		V <sub>CE</sub> =-2V, I <sub>c</sub> =-3A
V <sub>CE(sat)</sub>		-1.0	-1.5	V	I <sub>c</sub> =-3A, I <sub>B</sub> =-6mA
V <sub>BE(sat)</sub>		-1.6	-2.0	V	

### ● Diode for flyback voltage absorption (T<sub>a</sub>=25°C)

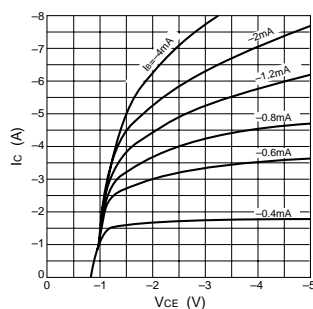
Symbol	Specification			Unit	Conditions
	min	typ	max		
V <sub>R</sub>	120			V	I <sub>R</sub> =10μA
V <sub>F</sub>			1.2	V	I <sub>F</sub> =1A
I <sub>R</sub>			10	μA	V <sub>R</sub> =120V
trr		100		ns	I <sub>F</sub> =±100mA

### ■ Equivalent circuit diagram

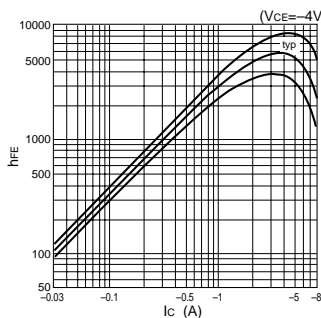


### ■ Characteristic curves

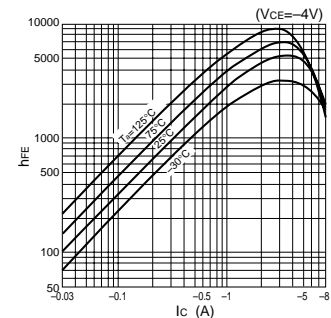
I<sub>c</sub>-V<sub>CE</sub> Characteristics (Typical)



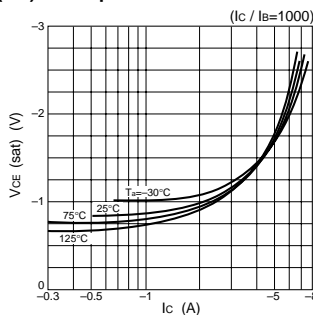
h<sub>FE</sub>-I<sub>c</sub> Characteristics (Typical)



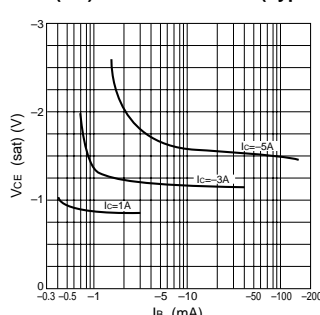
h<sub>FE</sub>-I<sub>c</sub> Temperature Characteristics (Typical)



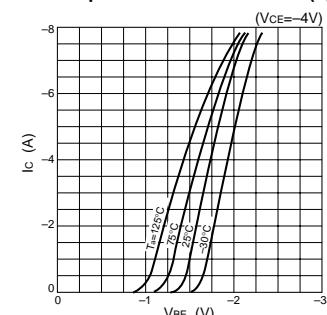
V<sub>CE(sat)</sub>-I<sub>c</sub> Temperature Characteristics (Typical)



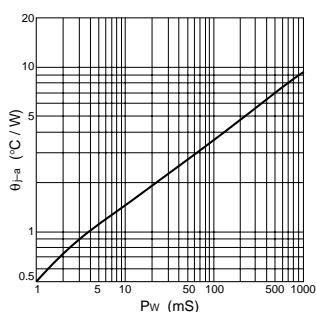
V<sub>CE(sat)</sub>-I<sub>B</sub> Characteristics (Typical)



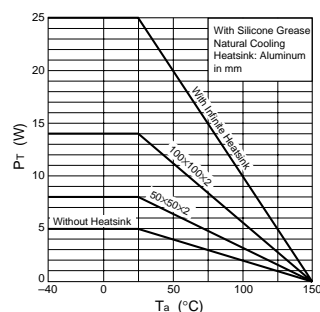
I<sub>c</sub>-V<sub>BE</sub> Temperature Characteristics (Typical)



θ<sub>J-a</sub>-P<sub>W</sub> Characteristics



P<sub>T</sub>-T<sub>a</sub> Characteristics



Safe Operating Area (SOA)

